

Parameter	Symbol	Value	Unit	
Diode reverse voltage	V <sub>R</sub>	40	V	
Forward current	/ <sub>F</sub>	250	mA	
Non-repetitive peak surge forward current	I <sub>FSM</sub>	800		
( <i>t</i> ≤ 10ms)				
Average rectified forward current (50/60Hz, sinus)	I <sub>FAV</sub>	120		
Total power dissipation	P <sub>tot</sub>		mW	
BAT64, <i>T</i> <sub>S</sub> ≤ 86°C		250		
BAT64-02W, -02V <i>T</i> <sub>S</sub> ≤ 121°C		250		
BAT64-04, BAT64-06, <i>T</i> <sub>S</sub> ≤ 61°C		250		
BAT64-04W, BAT64-06W, <i>T</i> <sub>S</sub> ≤ 111°C		250		
BAT64-05, <i>T</i> <sub>S</sub> ≤ 36°C		250		
BAT64-05W, <i>T</i> <sub>S</sub> ≤ 104°C		250		
Junction temperature	T <sub>j</sub>	150	°C	
Storage temperature	T <sub>stg</sub>	-55 150		

#### **Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup>	R <sub>thJS</sub>		K/W
BAT64		≤ 255	
BAT64-02W, -02V		≤ 115	
BAT64-04, BAT64-06,		≤ 355	
BAT64-04W, BAT64-06W		≤ 155	
BAT64-05		≤ <b>455</b>	
BAT64-05W		≤ 185	

<sup>1</sup>For calculation of  $R_{\text{thJA}}$  please refer to Application Note AN077 (Thermal Resistance Calculation)



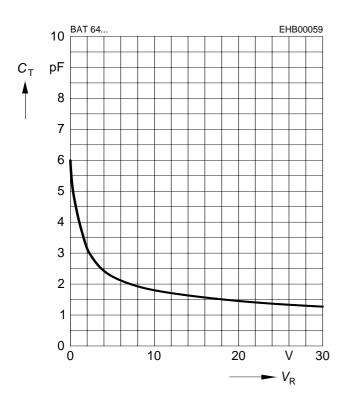
Parameter	Symbol		Unit		
		min.	typ.	max.	
DC Characteristics					
Breakdown voltage	V <sub>(BR)</sub>	40	-	-	V
<i>I</i> <sub>(BR)</sub> = 10 μA					
Reverse current	I <sub>R</sub>				μA
<i>V</i> <sub>R</sub> = 30 V		-	-	2	
<i>V</i> <sub>R</sub> = 30 V, <i>T</i> <sub>A</sub> = 85 °C		-	-	200	
Forward voltage	V <sub>F</sub>				mV
<i>I</i> <sub>F</sub> = 1 mA		270	320	350	
<i>I</i> <sub>F</sub> = 10 mA		310	385	430	
<i>I</i> <sub>F</sub> = 30 mA		370	440	520	
<i>I</i> <sub>F</sub> = 100 mA		500	570	750	
AC Characteristics	•	•	•	-	•
Diode capacitance	CT	-	4	6	pF
V <sub>R</sub> = 1 V, <i>f</i> = 1 MHz					
Reverse recovery time	t <sub>rr</sub>	-	-	5	ns
$I_{\rm F}$ = 10 mA, $I_{\rm R}$ = 10 mA, measured $I_{\rm R}$ = 1 mA ,					
R <sub>L</sub> = 100 Ω					

# **Electrical Characteristics** at $T_A$ = 25 °C, unless otherwise specified



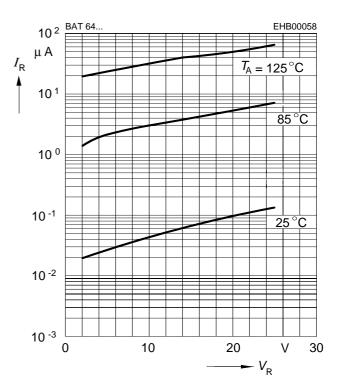
# **Diode capacitance** $C_{T} = f(V_{R})$

f = 1 MHz



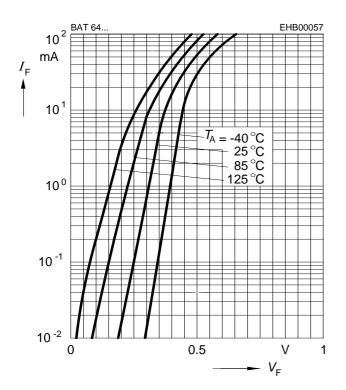
**Reverse current**  $I_{R} = f(V_{R})$ 

 $T_A$  = Parameter

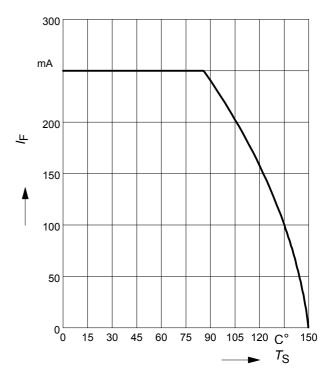


Forward current  $I_F = f(V_F)$ 

 $T_A$  = Parameter



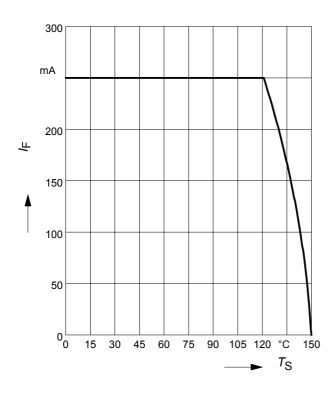
Forward current  $I_{\mathsf{F}} = f(T_{\mathsf{S}})$ BAT64



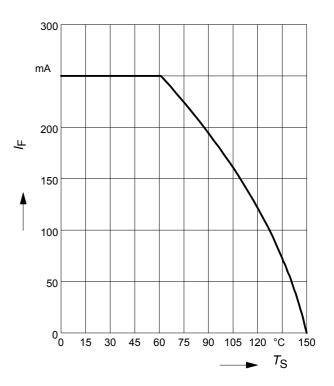


BAT64...

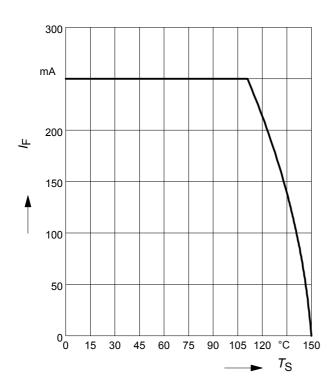
Forward current  $I_F = f(T_S)$ BAT64-02W, -02V



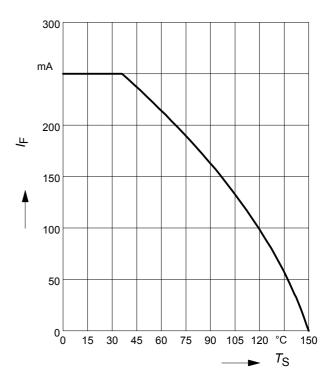
Forward current  $I_F = f(T_S)$ BAT64-04, BAT64-06



Forward current  $I_F = f(T_S)$ BAT64-04W, BAT64-06W



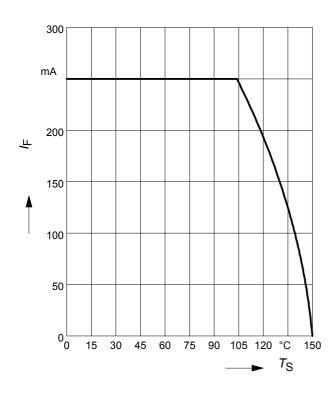
Forward current  $I_F = f(T_S)$ BAT64-05



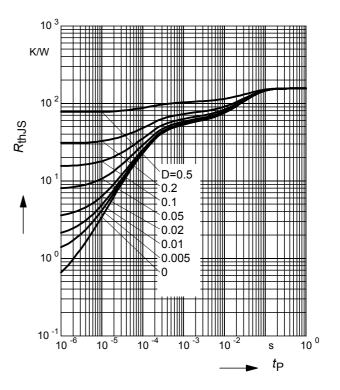


Forward current  $I_{\rm F}$  =  $f(T_{\rm S})$ 

BAT64-05W

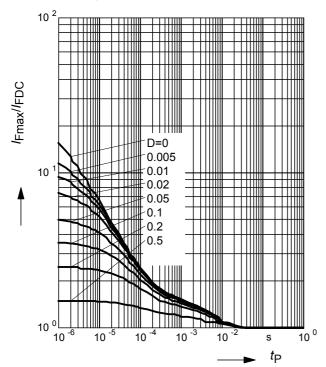


**Permissible Puls Load**  $R_{thJS} = f(t_p)$ BAT64-02W, -02V

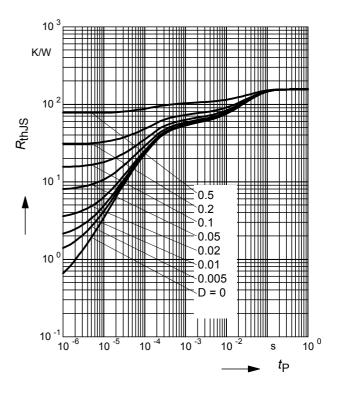


# Permissible Pulse Load

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAT64-02W, -02V



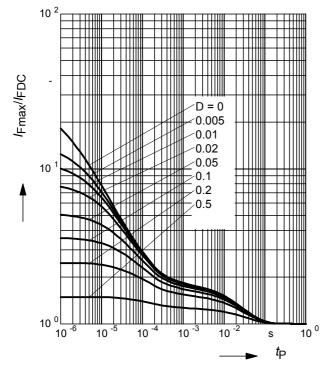
**Permissible Puls Load**  $R_{\text{thJS}} = f(t_p)$ BAT64-04W, BAT64-06W



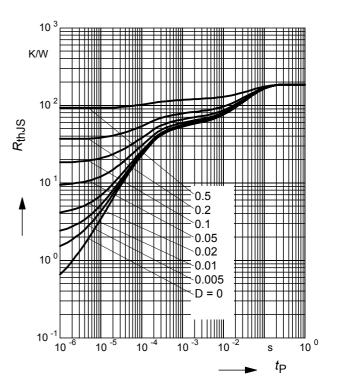


Permissible Pulse Load

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAT64-04W, BAT64-06W

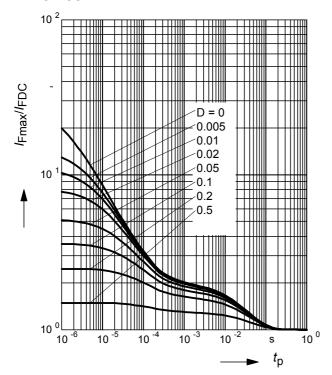


**Permissible Puls Load**  $R_{\text{thJS}} = f(t_p)$ BAT64-05W

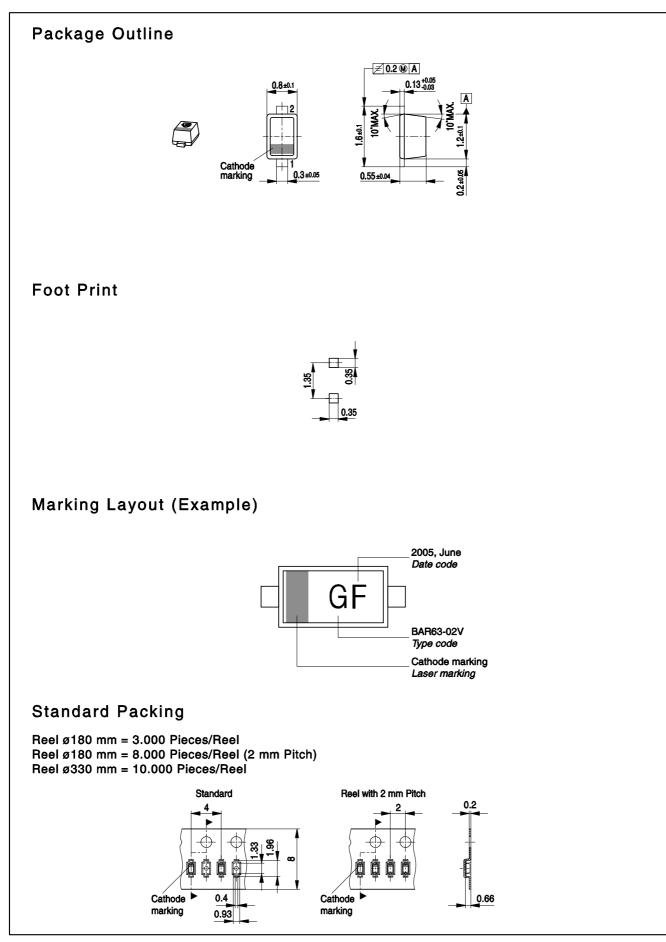


## Permissible Pulse Load

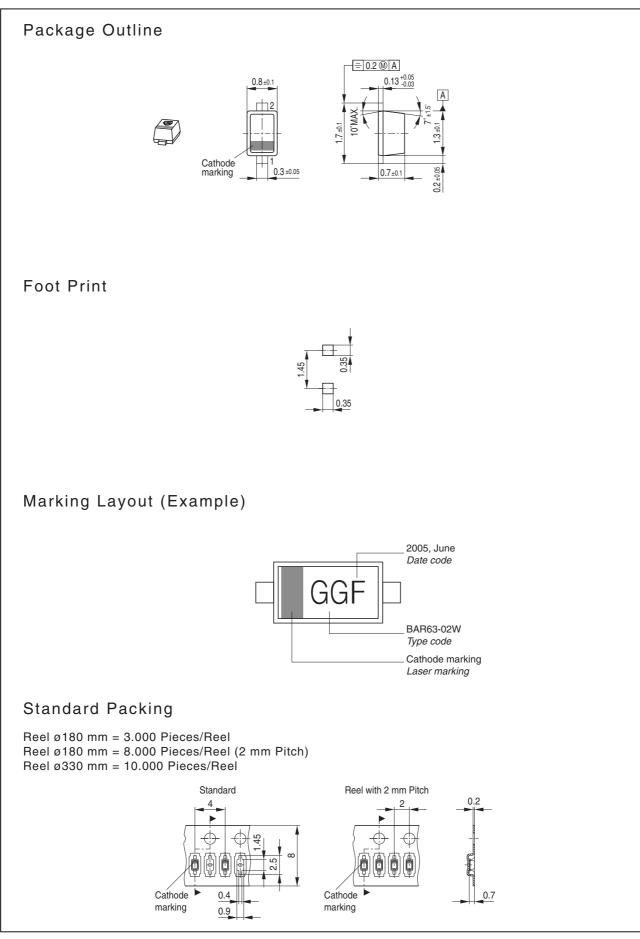
 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAT64-05W











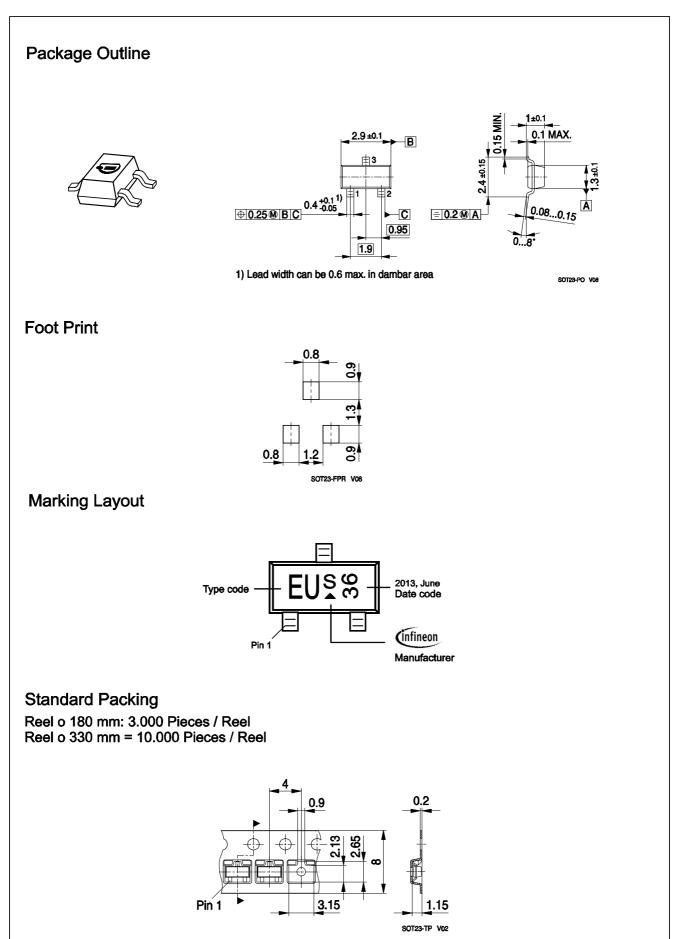


# Date Code marking for discrete packages with one digit (SCD80, SC79, SC75<sup>1)</sup>) CES-Code

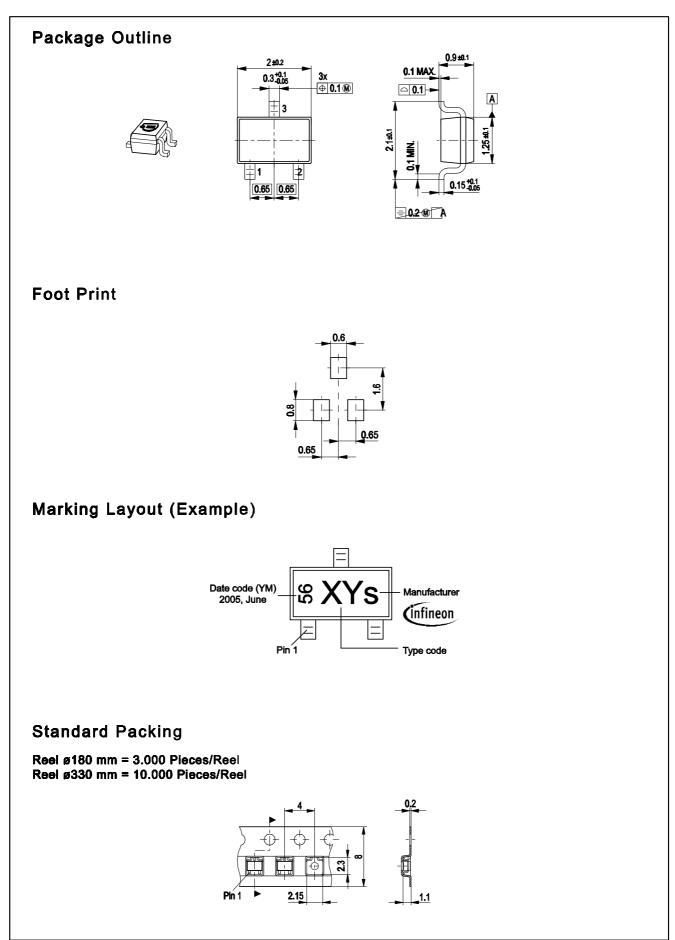
Month	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014
01	а	р	А	Р	а	р	А	Р	а	р	А	Р
02	b	q	В	Q	b	q	В	Q	b	q	В	Q
03	С	r	С	R	С	r	С	R	С	r	С	R
04	d	S	D	S	d	S	D	S	d	S	D	S
05	е	t	E	Т	е	t	E	Т	е	t	Е	Т
06	f	u	F	U	f	u	F	U	f	u	F	U
07	g	V	G	V	g	V	G	V	g	V	G	V
08	h	х	Н	Х	h	х	Н	Х	h	х	Н	Х
09	j	у	J	Y	j	у	J	Y	j	у	J	Y
10	k	Z	K	Z	k	Z	K	Z	k	Z	K	Z
11	I	2	L	4	I	2	L	4	I	2	L	4
12	n	3	Ν	5	n	3	Ν	5	n	3	Ν	5

1) New Marking Layout for SC75, implemented at October 2005.













Edition 2009-11-16

Published by Infineon Technologies AG 81726 Munich, Germany

© 2009 Infineon Technologies AG All Rights Reserved.

### Legal Disclaimer

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation, warranties of non-infringement of intellectual property rights of any third party.

### Information

For further information on technology, delivery terms and conditions and prices, please contact the nearest Infineon Technologies Office (<<u>www.infineon.com</u>>).

### Warnings

Due to technical requirements, components may contain dangerous substances. For information on the types in question, please contact the nearest Infineon Technologies Office.

Infineon Technologies components may be used in life-support devices or systems only with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.